

VERSACLOCK® LOW POWER CLOCK GENERATOR

IDT5P49EE602

Description

The IDT5P49EE602 is a programmable clock generator intended for low power, battery operated consumer applications. There are four internal PLLs, each individually programmable, allowing for up to six differrent output frequencies. The frequencies are generated from a single reference clock. The reference clock can come from either a TCXO or fundamental mode crystal. An additional 32.768kHz crystal oscillator is available to provide a real time clock or non-critical performance MHz processor clock.

The IDT5P49EE602 can be programmed through the use of the I²C interfaces. The programming interface enables the device to be programmed when it is in normal operation or what is commonly known as in system programmable. An internal EEPROM allows the user to save and restore the configuration of the device without having to reprogram it on power-up.

Each of the four PLLs has an 8-bit reference divider and a 11-bit feedback divider. This allows the user to generate four unique non-integer-related frequencies. The PLL loop bandwidth is programmable to allow the user to tailor the PLL response to the application. For instance, the user can tune the PLL parameters to minimize jitter generation or to maximize jitter attenuation.

Spread spectrum generation is supported on one of the PLLs. The device is specifically designed to work with display applications to ensure that the spread profile remains consistent for each HSYNC in order to reduce ROW noise. It also may operate in standard spread sepctrum mode.

There are total six 8-bit output dividers. The outputs are connected to the PLLs via the switch matrix. The switch matrix allows the user to route the PLL outputs to any output bank. This feature can be used to simplify and optimize the board layout. In addition, each output's slew rate and enable/disable function can be programmed.

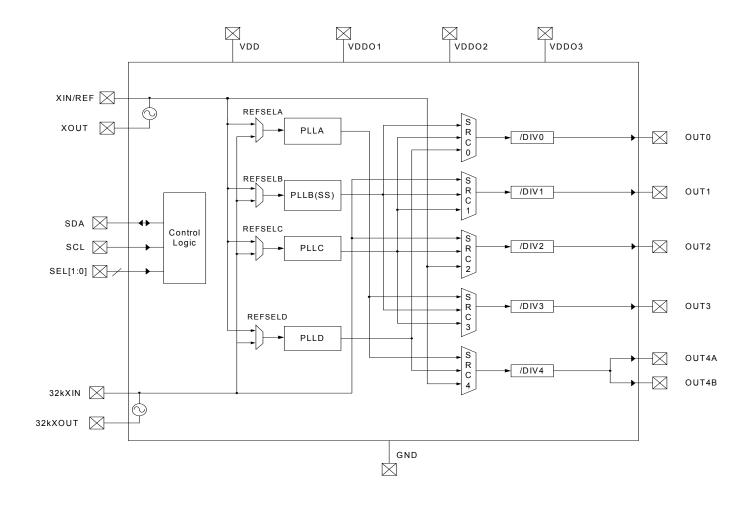
Target Applications

- · Smart Mobile Handset
- Personal Navigation Device (PND)
- Camcorder
- DSC
- Portable Game Console
- · Personal Media Player

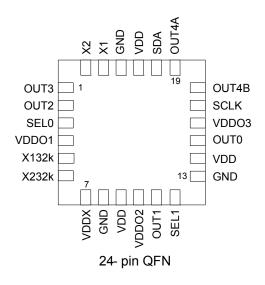
Features

- Four internal PLLs
- Internal non-volatile EEPROM
 - Internal I²C EEPROM master interface
- FAST (400kHz) mode I²C serial interfaces
- Input Frequencies
 - TCXO: 10 MHz to 40 MHzCrystal: 8 MHz to 30 MHzRTC Crystal: 32.768 kHz
- Output Frequency Ranges: kHz to 120 MHz
- Each PLL has an 8-bit reference divider and a 11-bit feedback-divider
- 8-bit output-divider blocks
- One of the PLLs support Spread Spectrum generation capable of configuration to pixel rate, with adjustable modulation rate and amplitude to support video clock with no visible artifacts
- I/O Standards:
 - Outputs 1.8V/2.5V/3.3 V LVTTL/ LVCMOS
- 3 independent adjustable VDDO groups.
- Programmable Slew Rate Control
- Programmable Loop Bandwidth Settings
- · Programmable output inversion to reduce bimodal jitter
- · Individual output enable/disable
- Power-down/Sleep mode
 - 10µA max in power down mode
 - 32kHz clock output active sleep mode
 - 100µA max in sleep mode
- 1.8V VDD Core Voltage
- Available in 24pin 4x4mm QFN packages
- -40 to +85 C Industrial Temp operation

Functional Block Diagram



Pin Assignment



Pin Descriptions

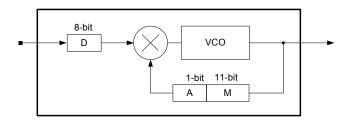
Pin Name	Pin #	I/O	Pin Type	Pin Description	
OUT3	1	0	Adjustable	Configurable clock output 3. Single-ended output voltage levels are register controlled by either VDDO1, VDDO2 or VDDO3.	
OUT2	2	0	Adjustable	Configurable clock output 2. Single-ended output voltage levare register controlled by either VDDO1, VDDO2 or VDDO3.	
SEL0	3	I	LVTTL	Configuration select pin. Weak internal pull down resistor.	
VDDO1	4		Power	Device power supply. Connect to 1.8 to 3.3V. Using register settings, select output voltage levels for OUT0-OUT4. VDDC must be greater than or equal to both VDDO2 and VDDO3.	
X132k	5	I	LVTTL	32kHz CRYSTAL_IN Reference crystal input	
X232k	6	0	LVTTL	32kHz CRYSTAL_OUT Reference crystal feedback.	
VDDx	7		Power	Crystal oscillator power supply. Connect to 1.8V. Use filtered analog power supply if available.	
GND	8		Power	Connect to Ground.	
VDD	9		Power	Device power supply. Connect to 1.8V.	
VDDO2	10		Power	Device power supply. Connect to 1.8 to 3.3V. Using register settings, select output voltage levels for OUT0-OUT3. VDDO2 must be equal or less than VDDO1.	
OUT1	11	0	Adjustable	Configurable clock output 1. Single-ended output voltage levels are register controlled by either VDDO1, VDDO2 or VDDO3.	
SEL1	12	I	LVTTL	Configuration select pin. Weak internal pull down resistor.	

GND	13		Power	Connect to Ground.
VDD	14		Power	Device power supply. Connect to 1.8V.
OUT0	15	0	Adjustable	Configurable clock output 0. Single-ended output voltage levels are register controlled by either VDDO1, VDDO2 or VDDO3.
VDDO3	16		Power	Device power supply. Connect to 1.8 to 3.3V. Using register settings, select output voltage levels for OUT0/3/6/7/8/9. VDDO3 must be equal or less than VDDO1.
SCLK	17	I	LVTTL	I ² C clock.
OUT4B	18	0	Adjustable	Configurable clock output 4B. Single-ended or differential when combined with OUT4A. Output voltage levels are controlled by VDDO1.
OUT4A	19	0	Adjustable	Configurable clock output 4A. Single-ended or differential when combined with OUT4B. Output voltage levels are controlled by VDDO1.
SDA	20	I/O	Open Drain	Bidirectional I ² C data.
VDD	21		Power	Device power supply. Connect to 18.V.
GND	22		Power	Connect to Ground.
XIN/ REF	23	I	LVTTL	MHz CRYSTAL_IN Reference crystal input or external reference clock input.
XOUT	24	0	LVTTL	MHz CRYSTAL_OUT Reference crystal feedback.

¹⁾ Outputs are user programmable to drive single-ended 1.8V/2.5V/3.3V LVTTL. Alway completely power up VDD and VDDx prior to applying VDDO power.

²⁾ Default configuration CLK1=Buffered MHz Reference output and CLK2=Buffered 32.768kHz output. All other outputs are off.

PLL Features and Descriptions



PLL Block Diagram

	Ref-Divider (D) Values	Feedback Pre-Divider (XDIV) Values	Feedback (M) Values	Programmable Loop Bandwidth	Spread Spectrum Generation Capability
PLLA	1 - 255	1 or 4 ¹	6 - 2047	Yes	No
PLLB	1 - 255	4	6 - 2047	Yes	Yes
PLLC	1 - 255	1 or 8 bit divide ²	6 - 2047	Yes	No
PLLD	1 - 255	1 or 4 ¹	6 - 2047	Yes	No

^{1.}XDIVA or XDIVD=0, A=1. XDIVA or XDIVD=1, A=4.

Crystal Input (XIN/REF)

The crystal oscillators should be fundamental mode quartz crystals; overtone crystals are not suitable. Crystal frequency should be specified for parallel resonance with 50Ω maximum equivalent series resonance.

Crystal Load Capacitors

The device crystal connections should include pads for small capacitors from X1 to ground and from X2 to ground. These capacitors are used to adjust the stray capacitance of the board to match the nominally required crystal load capacitance. Because load capacitance can only be increased in this trimming process, it is important to keep stray capacitance to a minimum by using very short PCB traces (and no vias) between the crystal and device. Crystal capacitors must be connected from each of the pins X1 and X2 to ground.

The crystal cpacitors are internal to the device and have an effective value of 8pF.

Reference Pre-Divider, Reference Divider, Feedback-Divider and Post-Divider

Each PLL incorporates an 8-bit reference-scaler and a 11-bit feedback divider which allows the user to generate four unique non-integer-related frequencies. PLLA and PLLD each have a feedback pre-divider that provides additional multiplication for kHz reference clock applications. Each output divider supports 8-bit post-divider. The following equation governs how the output frequency is calculated.

$$F_{OUT} = \frac{F_{IN} * \left(\frac{A*M}{D}\right)}{ODIV}$$
 (Eq. 2)

Where F_{IN} is the reference frequency, A is the feedback pre-divider value, M is the feedback-divider value, D is the reference divider value, ODIV is the total post-divider value, and F_{OUT} is the resulting output frequency. Programming any of the dividers may cause glitches on the outputs.

^{2.}XDIVC =0, A=1. XDIVC=1 turns on 8 bit predivide multiplier, A=FBC2[7:0]. Total feedback divide equals FBC[10:0] *FBC2[7:0].

SPREAD SPECTRUM GENERATION (PLLB)

PLLB has spread spectrum generation capability, which users have the option of turning on and off. Spread spectrum profile, frequency, and spread are fully programmable (within limits). The programmable spread spectrum generation parameters are NC[10:0], MOD[12:0], and NSS[10:0] bits. To enable spread spectrum, set SSENB B=0.

The spread spectrum circuitry was specifically developed to accommodate video display applications. The spread modulation frequency can be defined to exactly equal the horizontal line frequency (HSYNC)

NC[10:0]

These bits are used to determine the number of pulses per spread spectrum cycle. For video applications, NC is the number of pixels on the horizontal display row (or integer multiple of displayed pixels in a row). By matching the spread period to the screen, no tearing or "shimmer" will be apparent.

NC must be an even number to insure that the upward spread transition has the same number of steps as the downward spread transition.

For non-video applications, this can also be seen as the number of clock cycles for a complete spread spectrum period.

MOD[12:0]

These bits relate the VCO frequency to the target average spread output frequency (F_{MID}) .

$$F_{MID} = (F_{VCO}) / 8$$

$$F_{MAX} = F_{MID} + (SS\% * F_{MID})$$

$$F_{MIN} = F_{MID} - (SS\% * F_{MID})$$

$$MOD = (F_{REF}^* NC) / (2 * F_{MID})$$

NSS[10:0]

These bits control the amplitude of the spread modulation.

$$NSS = (NC/2) + (NC/8) * (F_{MAX} - F_{MIN}) / F_{MID}$$

Modulation frequency:

 $F_{MOD} = F_{MID} / NC$ (Eq. 11)

Video Example

 F_{REF} = 27 MHz, F_{OUT} = 27 MHz, 640 pixels per line, center spread of ±1%. Using F_{VCO} =432MHz, find the necessary spread spectrum register settings.

$$F_{MID} = F_{VCO}/8$$

NC = 640 (integer number of spread periods/screen)

$$MOD = (25MHz * 640)/(2 * 54MHz) = 160$$

NSS = (640/2) + (640/8) * (27.27MHz - 26.73MHz)/27MHz = 321.

 $F_{MOD} = 27MHz/640 = 11.8kHz.$

Non-Video Example

 F_{REF} = 25MHz, F_{OUT} = 27 MHz, 31.25kHz modulation rate, center spread of ±1%. Find the necessary spread spectrum register settings.

$$F_{MID} = F_{VCO} / 8$$

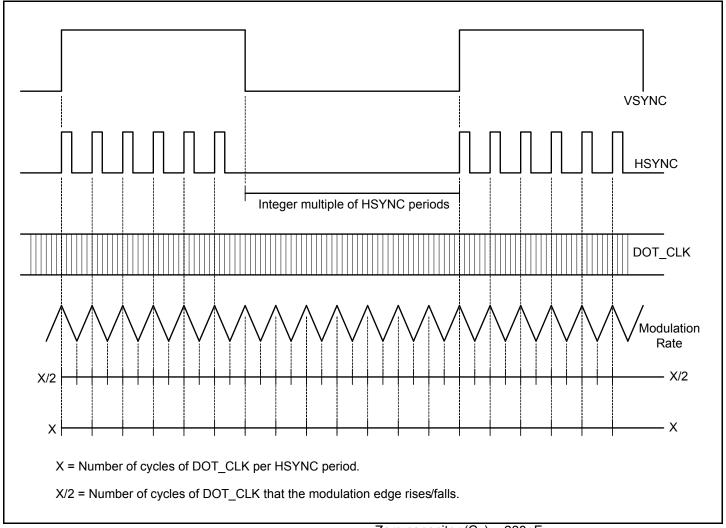
 $F_{MOD} = 31.25 \text{kHz} = 50.625 \text{MHz/NC}.$

NC = 1620

MOD = (25MHz * 1620)/(2 * 50.625MHz) = 400

NSS = (1620/2)+(1620/8)*(27.27MHz-26.73MHz)/27MHz = 814.

VSYNC, HSYNC, DOT_CLK - Modulation Rate Relationship



LOOP FILTER

The loop filter for each PLL can be programmed to optimize the jitter performance. The low-pass frequency response of the PLL is the mechanism that dictates the jitter transfer characteristics. The loop bandwidth can be extracted from the jitter transfer. A narrow loop bandwidth is good for jitter attenuation while a wide loop bandwidth is best for low jitter generation. The specific loop filter components that can be programmed are the resistor via the RZ[4:0] bits, zero capacitor via the CZ[2:0] bits, pole capacitor via the CP[1:0] bits, and the charge pump current via the IP#[2:0] bits.

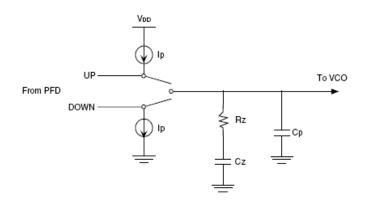
The following equations govern how the loop filter is set:

Zero capacitor (Cz) = 280pF

Pole capacitor (Cp) = 30pF

Charge pump (Ip) = IP#[2:0] uA

VCO gain (Kvco) = $350MHz/V * 2\pi$



PLL Loop Bandwidth:

Charge pump gain $(K\phi)$ = Ip / 2π

VCO gain (Kvco) = $950MHz/V * 2\pi$

M = Total multiplier value (See the PRE-SCALERS, FEEDBACK-DIVIDERS, POST-DIVIDERS section for more detail)

$$\omega c = (Rz * K \phi * Kvco * Cz)/(M * (Cz + Cp))$$

 $Fc = \omega c / 2\pi$

Note, the phase/frequency detector frequency (FPFD) is typically seven times the PLL closed-loop bandwidth (Fc) but too high of a ratio will reduce your phase margin thus compromising loop stability.

To determine if the loop is stable, the phase margin (ϕm) would need to be calculated as follows.

Phase Margin:

$$\omega z = 1 / (Rz * Cz)$$

$$\omega p = (Cz + Cp)/(Rz * Cz * Cp)$$

$$\phi m = (360 / 2\pi) * [tan^{-1}(\omega c / \omega z) - tan^{-1}(\omega c / \omega p)]$$

To ensure stability in the loop, the phase margin is recommended to be $> 60^{\circ}$ but too high will result in the lock time being excessively long. Certain loop filter parameters would need to be compromised to not only meet a required loop bandwidth but to also maintain loop stability.

Example

Fc = 150KHz is the desired loop bandwidth. The total A*M value is 160. The ζ (damping factor) target should be 0.7, meaning the loop is critically damped. Given Fc and A*M, an optimal loop filter setting needs to be solved for that will meet both the PLL loop bandwidth and maintain loop stability.

Choose a mid-range charge pump from register table

$$K\phi * Kvco = 300MHz/V * 40uA = 12000A/Vs$$

$$\omega c = 2\pi * Fc = 9.42x10^{5} s^{-1}$$

$$\omega p = (Cz + Cp)/(Rz * Cz * Cp) = \omega z (1 + Cz / Cp)$$

Solving for Rz, the best possible value Rz=30kOhms (RZ[1:0]=10) gives

$$\zeta = 1.2$$

Solving back for the PLL loop bandwidth, Fc=149kHz.

The phase margin must be checked for loop stability.

$$\phi m = (360 / 2\pi) * [tan_{-1} (9.42x10^5 s^{-1} / 1.19x10^5 s^{-1}) - tan_{-1}^{-1} (9.42x10^5 s^{-1} / 1.23x10^6 s^{-1})] = 45^{\circ}$$

The phase margin would be acceptable with a fairly stable loop.

SEL[1:0] Function

The IDT5P49EE602 can support up to three unique configurations. Users may pre-programmed all these configurations, and select the configurations using SEL[1:0] pins. Alternatively, users may use I2C interface to configure these registers on- the-fly.

Always power with SEL1=1 and/or SEL0=1.

Power Down/Sleep Mode is selected by the No_PD bit. No_PD=0 enables Power Down mode with no outputs. No_PD=1 enables sleep mode with 32kHz output on OUT4.

SEL1	SEL0	Configuration Selections
0	0	Power Down/Sleep Mode
0	1	Select CONFIG0
1	0	Select CONFIG1
1	1	Select CONFIG2

Configuration OUTx IO Standard

Users can configure the individual output IO standard from

a single 3.3V power supply. Each output can support 1.8V/2.5V or 3.3V LVCMOS. VDDO1 must have the highest voltage of any pin on the device. VDDO2 and VDDO3 may have any value between 1.8V and VDDO1.

The frame formats are shown in the following illustration.

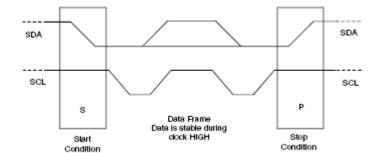
Programming the Device

I²C may be used to program the IDT5P49EE602.

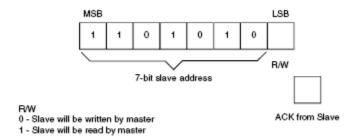
- Device (slave) address = 7'b1101010

I²C Programming

The IDT5P49EE602 is programmed through an I2C-Bus serial interface, and is an I2C slave device. The read and write transfer formats are supported. The first byte of data after a write frame to the correct slave address is interpreted as the register address; this address auto-increments after each byte written or read.



Framing



The first byte transmitted by the Master is the Slave Address followed by the R/W bit. The Slave acknowledges by sending a "1" bit.

First Byte Transmitted on I²C Bus

External I²C Interface Condition

KEY:

From Master to Slave

From Master to Slave, but can be omitted if followed by the correct sequence

Normally data transfer is terminated by a STOP condition generated by the Master. However, if the Master still wishes to communicate on the bus, it can generate a repeated START condition, and address another Slave address without first generating a STOP condition.

From Slave to Master

SYMBOLS:

ACK - Acknowledge (SDA LOW)
NACK - Not Acknowledge (SDA HIGH)
Sr - Repeated Start Condition

S - START Condition

P-STOP Condition

EEPROM Interface

The IDT5P49EE602 can store its configuration in an internal EEPROM. The contents of the device's internal programming registers can be saved to the EEPROM by issuing a save instruction (ProgSave) and can be loaded back to the internal programming registers by issuing a restore instruction (ProgRestore).

To initiate a save or restore using I²C, only two bytes are transferred. The Device Address is issued with the read/write bit set to "0", followed by the appropriate command code. The save or restore instruction executes

after the STOP condition is issued by the Master, during which time the IDT5P49EE602 will not generate Acknowledge bits. The IDT5P49EE602 will acknowledge the instructions after it has completed execution of them. During that time, the I²C bus should be interpreted as busy by all other users of the bus.

On power-up of the IDT5P49EE602, an automatic restore is performed to load the EEPROM contents into the internal programming registers. The IDT5P49EE602 will be ready to accept a programming instruction once it acknowledges its 7-bit I²C address.

Progwrite

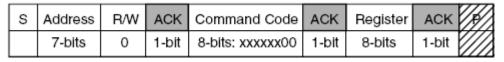
s	Address	R/W	ACK	Command Code	ACK	Register	ACK	Data	ACK	Р	
	7-bits	0	1-bit	8-bits: xxxxxx00	1-bit	8-bits	1-bit	8-bits	1-bit		

Progwrite Command Frame

Writes can continue as long as a Stop condition is not sent and each byte will increment the register address.

Progread

Note: If the expected read command is not from the next higher register to the previous read or write command, then set a known "read" register address prior to a read operation by issuing the following command:



Prior to Progread Command Set Register Address

The user can ignore the STOP condition above and use a repeated START condition instead, straight after the slave acknowledgement bit (i.e., followed by the Progread command):

Sr	Address	R/W	ACK	ID Byte	ACK	Data_1	ACK	Data_2	ACK	Data_last	NACK	Р
	7-bits	1	1-bit	8 bits	1-bit	8-bits	1-bit	8-bits	1-bit	8-bits	1-bit	

Progread Command Frame

Progsave

s	Address	R/W	ACK	Command Code	ACK	Р
	7-bits	0	1-bit	8-bits:xxxxxx01	1-bit	

Note:

PROGWRITE is for writing to the IDT5P49EE602 registers. PROGREAD is for reading the IDT5P49EE602 registers. PROGSAVE is for saving all the contents of the IDT5P49EE602 registers to the EEPROM. PROGRESTORE is for loading the entire EEPROM contents to the IDT5P49EE602 registers.

Progrestore

s	Address	R/W	ACK	Command Code	ACK	Р
	7-bits	0	1-bit	8-bits:xxxxxx10	1-bit	

During PROGRESTORE, outputs will be turned off to ensure that no improper voltage levels are experienced before initialization.

I²C Bus DC Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{IH}	Input HIGH Level		0.7xVDD		5.5	V
V _{IL}	Input LOW Level				0.3xVDD	V
V _{HYS}	Hysteresis of Inputs		0.05xVDD			V
I _{IN}	Input Leakage Current	$V_{DD} = 0V$			±1.0	μΑ
V _{OL}	Output LOW Voltage	I _{OL} = 3 mA			0.4	V

I²C Bus AC Characteristics for Standard Mode¹

Symbol	Parameter	Min	Тур	Max	Unit
F _{SCLK}	Serial Clock Frequency (SCL)	0		100	kHz
t _{BUF}	Bus free time between STOP and START	4.7			μs
t _{SU:START}	Setup Time, START	4.7			μs
t _{HD:START}	Hold Time, START	4			μs
t _{SU:DATA}	Setup Time, data input (SDA)	250			ns
t _{HD:DATA}	Hold Time, data input (SDA) ²	0			μs
t _{OVD}	Output data valid from clock			3.45	μs
C _B	Capacitive Load for Each Bus Line			400	pF
t _R	Rise Time, data and clock (SDA, SCLK)			1000	ns
t _F	Fall Time, data and clock (SDA, SCLK)			300	ns
t _{HIGH}	HIGH Time, clock (SCLK)	4			μs
t _{LOW}	LOW Time, clock (SCLK)	4.7			μs
t _{SU:STOP}	Setup Time, STOP	4			μs

¹⁾ No activity is allowed on I²C lines until VDD>1.62V.

²⁾ A device must internally provide a hold time of at least 300 ns for the SDA signal (referred to the $V_{IH}MIN$ of the SCL signal) to bridge the undefined region of the falling edge of SCL.

I²C Bus AC Characteristics for Fast Mode¹

Symbol	Parameter	Min	Тур	Max	Unit
F _{SCLK}	Serial Clock Frequency (SCL)	0		400	kHz
t _{BUF}	Bus free time between STOP and START	1.3			μs
t _{SU:START}	Setup Time, START	0.6			μs
t _{HD:START}	Hold Time, START	0.6			μs
t _{SU:DATA}	Setup Time, data input (SDA)	100			ns
t _{HD:DATA}	Hold Time, data input (SDA) ²	0			μs
t _{OVD}	Output data valid from clock			0.9	μs
C _B	Capacitive Load for Each Bus Line			400	pF
t _R	Rise Time, data and clock (SDA, SCL)	20 + 0.1xC _B		300	ns
t _F	Fall Time, data and clock (SDA, SCL)	20 + 0.1xC _B		300	ns
t _{HIGH}	HIGH Time, clock (SCL)	0.6			μs
t _{LOW}	LOW Time, clock (SCL)	1.3			μs
t _{SU:STOP}	Setup Time, STOP	0.6			μs

¹⁾ No activity is allowed on I²C lines until VDD>1.62V.

²⁾ A device must internally provide a hold time of at least 300 ns for the SDA signal (referred to the $V_{IH}MIN$ of the SCL signal) to bridge the undefined region of the falling edge of SCL.

Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the IDT5P49EE602. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

Symbol	Description	Max	Unit
V _{DD}	Internal Power Supply Voltage	-0.5 to +4.6	V
VI	Input Voltage	-0.5 to +4.6	٧
V _O	Output Voltage (not to exceed 4.6 V)	-0.5 to V _{DD} +0.5	V
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-65 to +150	°C

Recommended Operation Conditions

Symbol	Parameter	Min	Тур	Max	Unit
V_{DD}	Power supply voltage for core VDD	1.62	1.8	1.98	V
T _A	Operating temperature, ambient	-40		+85	°C
C _{LOAD_OUT}	Maximum load capacitance (3.3V LVTTL only)			15	pF
C _{LOAD_OUT}	Maximum load capacitance (1.8V or 2.5V LVTTL only)			8	pF
F _{IN}	External reference crystal	8		30	MHz
	External reference clock CLKIN	1		40	
t _{PU}	Power up time for all V _{DD} s to reach minimum specified voltage (power ramps must be monotonic)	0.05		5	ms

Capacitance $(T_A = +25 \, ^{\circ}\text{C}, f = 1 \, \text{MHz}, V_{IN} = 0\text{V})$

Symbol	Parameter	Min	Тур	Max	Unit
C _{IN}	Input Capacitance		3		pF
Crystal Specif	ications				
XTAL_FREQ	Crystal frequency	8		30	MHz
XTAL_MIN	Minimum crystal load capacitance		TBD		pF
XTAL_MAX	Maximum crystal load capacitance		35.4		pF
XTAL_V _{PP}	Voltage swing (peak-to-peak, nominal)	1.5	2.3	3.2	V

DC Electrical Characteristics for 3.3 Volt LVTTL ¹

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
V _{OH}	Output HIGH Voltage	I _{OH} = 33mA	2.4		VDDO	٧
V _{OL}	Output LOW Voltage	I _{OH} = 33mA			0.4	٧
V _{IH}	Input HIGH Voltage		2			٧
V _{IL}	Input LOW Voltage				0.8	٧
I _{OZDD}	Output Leakage Current	3-state outputs			5	μΑ

DC Electrical Characteristics for 2.5Volt LVTTL ¹

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
V _{OH}	Output HIGH Voltage	I _{OH} = 25mA	2.1		VDDO	٧
V_{OL}	Output LOW Voltage	I _{OH} = 25mA			0.4	V
I _{OZDD}	Output Leakage Current	3-state outputs			5	μΑ

DC Electrical Characteristics for 1.8Volt LVTTL ¹

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
V _{OH}	Output HIGH Voltage	VDD = 1.71V to 1.89V	0.65*VDDO		VDDO	٧
V_{OL}	Output LOW Voltage				0.35*VDDO	٧
I _{OZDD}	Output Leakage Current	3-state outputs			5	μΑ

Power Supply Characteristics for LVTTL Outputs

Symbol	Parameter	Test Conditions	Тур	Max	Unit
I _{TOT}	Total Power VDD Supply Current	F _{REFERENCE CLOCK} = 25 MHz, C _L = 7 pF	TBD		mA

Note 1: See "Recommended Operating Conditions" table. Alway completely power up VDD and VDDx prior to applying VDDO power.

AC Timing Electrical Characteristics

(Spread Spectrum Generation = OFF)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
f _{IN}	Input Frequency	Input Frequency Limit (CLKIN)	1 ¹		40	MHz
1 / t1	Output Frequency	Single Ended Clock output limit (LVTTL) 3.3V	0.001		120	MHz
		Single Ended Clock output limit (LVTTL) 2.5V	_		110	MHz
		Single Ended Clock output limit (LVTTL) 1.8V			100	MHz
f _{VCO}	VCO Frequency	VCO operating Frequency Range	100		475	MHz
f _{PFD}	PFD Frequency	PFD operating Frequency Range	0.300 1		20	MHz
t2	Input Duty Cycle	Duty Cycle for Input	40		60	%
t3	Output Duty Cycle	Measured at VDD/2	45		55	%
t4	Slew Rate, SLEWx(bits) = 00	Single-Ended 3.3V LVCMOS Output clock rise and fall time, 20% to 80% of VDD (Output Load = 7 pF)		3.5		V/ns
	Slew Rate, SLEWx(bits) = 01	Single-Ended 3.3V LVCMOS Output clock rise and fall time, 20% to 80% of VDD (Output Load = 7 pF)		2.75		
	Slew Rate, SLEWx(bits) = 10	Single-Ended 3.3V LVCMOS Output clock rise and fall time, 20% to 80% of VDD (Output Load = 7 pF)		2		
	Slew Rate, SLEWx(bits) = 11	Single-Ended 3.3V LVCMOS Output clock rise and fall time, 20% to 80% of VDD (Output Load = 7 pF)		1.25		
t5	Clock Jitter	Peak-to-peak period jitter, CLK outputs measured at VDD/2; f _{PFD} >= 10 MHz Single output frequency only.			100	ps
		Peak-to-peak period jitter, CLK outputs measured at VDD/2; f _{PFD} >= 10 MHz Multiple output frequencies switching.			200	ps
t6	Output Skew	Skew between output to output on the same bank			75	ps
		Skew between any output (Same freq and IO type, FOUT >10MHz)			200	ps
t7	Lock Time	PLL Lock Time from Power-up (using MHz reference clock) ²		5	20	ms
		PLL Lock Time from Power-up using 32.768kHz reference clock)		1	3	S
		PLL Lock time from shutdown mode			5	ms

¹⁾ Input clock (square wave) may be used at 1 MHz.

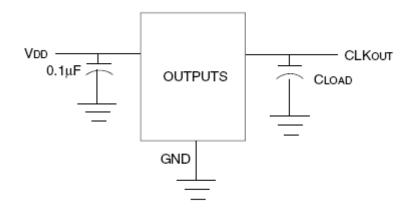
²⁾ Time from supply voltage crosses VDD=1.62V to PLLs are locked.

Spread Spectrum Generation Specifications

Symbol	Parameter	Description	Min	Тур	Max	Unit
f _{IN}	Input Frequency	Input Frequency Limit	1 ¹		40	MHz
f _{MOD}	Mod Frequency	Modulation Frequency	32		120	kHz
f _{SPREAD}	Spread Value	Amount of Spread Value (programmable) - Down Spread	Pro	gramm	able	%f _{OUT}
		Amount of Spread Value (programmable) - Center Spread	Pro	gramm	able	

Note 1: Practical lower frequency is determined by loop filter settings.

Test Circuits and Conditions ¹

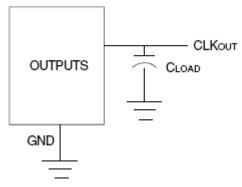


NOTE:

1. All Vco pins must be tied together.

Test Circuits for DC Outputs

Other Termination Scheme (Block Diagram)



LVTTL: ~7pF for each output

Programming Registers Table

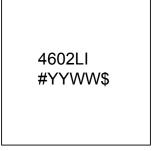
Hex		Default				E	Bit #				
CSX[1:0] - Internal Salktz cystal case Cox 10 - 30F 11 - 3	Addr	_	7	6	5	4	3	2	1	0	Description
Oxide Oxide Oxide Reserved Oxide O	0x00						1[1:0]	XTAL32ONB			CSX2 [1:0]- internal 32kHz crystal cap2 00 - 18pF; 10 - 30pF 01 - 24pF; 11 - 36pF CSX1 [1:0] - Internal 32kHz crystal cap1 00 - 0pF; 10 - 6pF 01 - 3pF; 11 - 9pF XTAL32ONB - 32k crystal active low
No. Pob. - 32kHz soff No. No. Pob. - 32kHz soff No. - 32			INV[0]	SLEW	/0[0:1]	_		S0[2:1]	R	eserved	
No.											
State Stat			INIV/641	CI EM	(410.41			2410-41			
No.			INV[1]	SLEW	11[0:1]			51[2:1]	н	eserved	
No.											0 0 - 5.1V/ns
11 - 1,8 V/ns			INV[2]	SLEW	/2[0·1]			S22·11	B	eserved	
No.								-			1 1 - 1.8V/ns
No	0x09	00		INV[4A] SLEW4[0:1] Reserved							00 - Reserved 01 - CLK# connects to VDDO1 10 - CLK# connects to VDDO2
OXCC 00 Reserved 0x0D 00 REFA[7:0] Configuration (REFA[7:0] - Reference Divide PLLA) 0x0F 00 FBA[10:3) FBA[10:0] - Feedback Divide PLLA 0x10 00 Reserved FBA[10:0] - Feedback Divide PLLA; 0.71; 1 - /4 RZA[1:0] - Zero Resistor PLLA (0.71; 1 - /4 RZA[1:0] - Zero Res	0x0A	00	l			Re	served				
Ox0D O0	0x0B										
Note											
Note											
Nation N											REFA[7:0] - Reference Divide PLLA
Nation N					December	FB.	A[10:3)		EDA(O.O)		FBA[10:0] - Feedback Divide PLLA
0 - /1; 1 - /4 RZA[1:0] - Zero Resistor PLLA 00 - 5kOhm 01 - 10kOhm 01 - 10kOhm 10 - 30kOhm 11 - 80kOhm 11 - 12.7 uA 110 - 17.7 uA 111 - 22.7 uA REFSILA - Clock input PLLA 0 - MHz input 1 - 3zkHz input 1 -			Danamand	VDIVA		7.014.01		IDA(O.O)	FBA[2:0)	DEECELA	VDIVA ED avadicida DI LA
0x13 00 FBB[10:3] FBB[10:0] - Feedback Divide PLLB 0x14 00 MOD[4:0] FBB[2:0] PLLB Spread Parameters MOD[12:0] 0x15 00 MOD[12:5] NC[10:0] NSS[12:0] 0x16 00 NSS[4:0] NC[2:0]			neserved	XDIVA	H2			IFA[2:U]		HEFSELA	0 - /1; 1 - /4 RZA[1:0] - Zero Resistor PLLA 00 - 5kOhm 10 - 10kOhm 10 - 30kOhm 11 - 80kOhm 11 - 80kOhm IPA[2:0] - charge Pump Current PLLA 100 - 6.3uA 101 - 11.9 uA 110 - 17.7 uA 111 - 22.7uA REFSELA - Clock input PLLA 0 - MHz input 1 - 32kHz input
0x14 00 MOD[4:0] FBB[2:0] PLLB Spread Parameters MOD[12:0] 0x15 00 MOD[12:5] NC[10:0] 0x16 00 NC[10:3] 0x17 00 NSS[4:0] NC[2:0]	_										
0x15 00 MOD[12:5] NC[10:0] 0x16 00 NC[10:3] 0x17 00 NSS[4:0] NC[2:0]						FB	B[10:3]				
0x16 00 NC[10:3] 0x17 00 NSS[4:0]					MOD[4:0]		D110 =		FBB[2:0]		
0x17 00 NSS[4:0] NC[2:0]											NSS[12:0]
					NSSI4-01	NC	ال.ان.		NCIO·OI		_
	0x17 0x18	00			1400[4.0]	NS	S[12·5]		140[2.0]		+

	Default									
Addr	Register Hex Value	7	6	5	4	3	2	1	0	Description
0x19 0x1A	20 00		Reserved IPB[2:0] RZB[1:0] Reserved REFSELB SSENB_B					RZB[1:0] - Zero Resistor PLLB 00 - 5kOhm 01 - 10kOhm 10 - 30kOhm 11 - 80kOhm IPB[2:0] - charge Pump Current PLLB 000 - 0.37uA, 100 - 6.3uA 001 - 1.1uA, 101 - 11.9uA 010 - 1.8 uA, 110 - 17.7uA		
0x1B	00				RE	FC[7:0]				REFSELB - Clock input PLLB 0 - MHz input 1 - 32kHz input REFC[7:0] - Reference Divide PLLC
0x1C	00					C[10:3]				FBC[10:0] - Feedback Divide PLLC
0x1D	00			Reserved	1.0	0[10.0]		FBC[2:0]		De[10.0] Toodback Divide 1 EEG
0x1E	00			110001100	FB	C2[7:0]		. 20[2.0]		FBC2 - Feedback Predivide PLLC Turn on using XDIVC=1
0x1F	00	IPC[2:0] RZC[1:0] Reserved XDIVC REFSELC					RZC[1:0] - Zero Resistor PLLC 00 - 5kOhm 01 - 10kOhm 11 - 80kOhm 11 - 80kOhm 11 - 80kOhm 1PC[2:0] - charge Pump Current PLLC 100 - 6.3uA 101 - 11.9 uA 110 - 17.7 uA 111 - 22.7uA REFSELC 0 - MHz input 1 - 32kHz input			
0x20	00				RE	FD[7:0]				REFD[7:0] - Reference Divide PLLD
0x21	00				FB	D[10:3]	1			FBD[10:0] - Feedback Divide PLLD
0x22 0x23	00	XDIVD	RZD	Reserved FBD[2:0] RZD[1:0] IPD[2:0] REFSELD[1:0]			XDIVD - FB predivide PLLD; 0 - /1; 1 - /4 RZD[1:0] - Zero Resistor PLLD 00 - 5kOhm 01 - 10kOhm 10 - 30kOhm 11 - 80kOhm IPD[2:0] - charge Pump Current PLLD 100 - 6.3uA 101 - 11.9 uA 111 - 22.7uA REFSELD[1:0] 00 - MHz input 11 - 32kHz input Others - Reserved			
0x24	00		•		OI	D0[7:0]				OD#[7:0] - Output Divide#
0x25	00									
0x26	00					eserved				
0x27	00					D1[7:0]				
0x28	00					eserved				
0x29	00					eserved				
0x2A	00					D2[7:0]				
0x2B	00	OD3[7:0]								_
0x2C	00				OI	D4[7:0]				

	Default Register		T	T	E	Bit #	T	I		
Addr	Hex Value	7	6	5	4	3	2	1	0	Description
0x2D	00		4[1:0]		3[1:0]		[] [2[1:0]		served	SRC4[1:0] - OD4 source 00 - off; 10 - PLLC 01 - PLLA; 11 - MHz Reference SRC3[1:0] - OD3 source 00 - off; 10 - PLLA 01 - PLLC; 11 - PLLB SRC2[1:0] - OD2 source 00 - off; 10 - MHz Reference 01 - PLLC; 11 - 32kHz Reference
0x2E	00		erved	SCR	1[1:0]		erved	Re:	served	SRC1[1:0] - OD1 source 00 - off; 10 - PLLB 01 - 32kHz Reference; 11 - PLLD
0x2F	00	SCR	0[1:0]				eserved			SRC0[1:0] - OD0 source 00 - off; 10 - PLLC
0x30	00				Re	served				01 - PLLB; 11 - PLLD
0x31	00	PDB[4]	Reserved	OE[4B]	OE[4A]		Re	served		PDB[#] - Powerdown OUT#. PDB#=0,
0x32	00	OE[3]	OE[2]	Reserved	Reserved	OE[1]	Reserved	Reserved	OE[0]	OUT# driven low OE[#] - Output enable OUT#. OE#=0,
0x33	00	PDB[3]	PDB[2]	Reserved	Reserved	PDB[1]	Reserved	Reserved	PDB[0]	OUT# tri-stated. If PDB#=OE#=0, OUT# driven low
0x34	00				RE	FA[7:0]				Configuration1
0x35	00				FB	A[10:3)				(See definitions from Configuration0 above)
0x36	00			Reserved				FBA[2:0)		above)
0x37	00	Reserved	XDIVA	RZA	(1:0]		IPA[2:0]		REFSELA	
0x38	00				RE	FB[7:0]				
0x39	00				FB	B[10:3]				
0x3A	00			MOD[4:0]				FBB[2:0]		
0x3B	00					D[12:5]				
0x3C	00				NO	C[10:3]	Т			
0x3D	00			NSS[4:0]		0110 51		NC[2:0]		
0x3E 0x3F	00 40		Reserved		NS	S[12:5] IPB[2:0]		D7	B[1:0]	_
0x3F	00		neserveu	Base	erved	IPB[2.0]		REFSELB	SSENB_B	_
0x40 0x41	00			11030		FC[7:0]		TIET SEED	SSEND_D	_
0x42	00					C[10:3]				_
0x43	00			Reserved		-[]		FBC[2:0]		_
0x44	00				FB	C2[7:0]				
0x45	00		IPC[2:0]		RZC	C[1:0]	Reserved	XDIV	REFSELC	
0x46	00				RE	FD[7:0]				
0x47	00				FB	D[10:3]				
0x48	00			Reserved				FBD[2:0]		
0x49	00	XDIVD	RZI	0[1:0]		IPD[2:0]		REFS	ELD[1:0]	
0x4A	00					00[7:0]				_
0x4B	00					served				_
0x4C 0x4D	00					served D1[7:0]				_
0x4D 0x4E	00					served				_
0x4E	00					served				-
0x50	00					D2[7:0]				
0x51	00					D3[7:0]				+
0x52	00					D47:0]				+
0x53	00	SCR	4[1:0]	SCR	3[1:0]		21:0]	Re	served	
0x54	00		erved		1[1:0]		erved	Re	served	
0x55	00	SCR	0[1:0]			Re	served	1		
0x56	00					served				
0x57	00	PDB[4]	Reserved	OE[4B]	OE[4A]		Re	served		
0x58	00	OE[3]	OE[2]	Reserved	Reserved	OE[1]	Reserved	Reserved	OE[0]	
0x59	00	PDB[3]	PDB[2]	Reserved	Reserved	PDB[1]	Reserved	Reserved	PDB[0]	

	Default									
Addr	Register Hex Value	7	6	5	4	3	2	1	0	Description
0x5A	00				RE	FA[7:0]				Configuration2
0x5B	00	FRA(10:3) (See definitions fro							(See definitions from Configuration0	
0x5C	00	Reserved FBA[2:0)						above)		
0x5D	00	Reserved	XDIVA		[1:0]		IPA[2:0]	. ,	REFSELA	+
0x5E	00					FB[7:0]				_
0x5F	00				FB	B[10:3]				
0x60	00			MOD[4:0]				FBB[2:0]		
0x61	00				MC	D[12:5]				
0x62	00				N	C[10:3]				
0x63	00			NSS[4:0]				NC[2:0]		
0x64	00				NS	S[12:5]				
0x65	40		Reserved			IPB[2:0]		RZ	B[1:0]	
0x66	00			Rese	erved			REFSELB	SSENB_B	
0x67	00				RE	FC[7:0]			l .	
0x68	00				FB	C[10:3]				
0x69	00			Reserved				FBC[2:0]		
0x6A	00				FB	C2[7:0]				
0x6B	00		IPC[2:0]		RZO	C[1:0]	Reserved	XDIV	REFSELC	
0x6C	00				RE	FD[7:0]			1	
0x6D	00				FB	D[10:3]				
0x6E	00			Reserved				FBD[2:0]		
0x6F	00	XDIVD	RZD	[1:0]		IPD[2:0]		REFS	ELD[1:0]	
0x70	00				OI	D0[7:0]				
0x71	00				Re	served				
0x72	00					eserved				
0x73	00					D1[7:0]				
0x74	00					eserved				
0x75	00					eserved				
0x76	00					D2[7:0]				
0x77	00					D3[7:0]				
0x78	00					D4[7:0]				
0x79	00		4[1:0]	SCR			2[1:0]		served	
0x7A	00		erved	SCR	1[1:0]		erved	Re	served	
0x7B	00	SCR	0[1:0]				served			
0x7C	00					served				
0x7D	00	PDB[4]	Reserved	OE[4B]	OE[4A]			served		
0x7E	00	OE[3]	OE[2]	Reserved	Reserved	OE[1]	Reserved	Reserved	OE[0]	
0x7F	00	PDB[3]	PDB[2]	Reserved	Reserved	PDB[1]	Reserved	Reserved	PDB[0]	

Marking Diagram (NL24)



Notes:

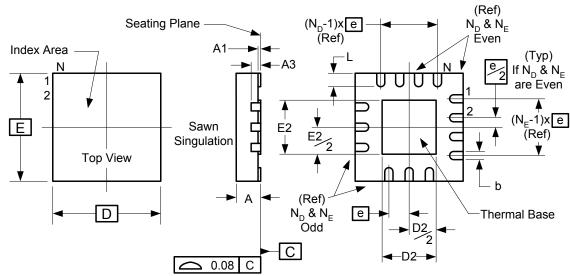
- 1. "Z" is the device step (1 to 2 characters).
- 2. YYWW is the last two digits of the year and week that the part was assembled.
- 3. "\$" is the assembly mark code.
- 4. "G" after the two-letter package code designates RoHS compliant package.
- 5. "I" at the end of part number indicates industrial temperature range.
- 6. Bottom marking: country of origin if not USA.

Thermal Characteristics for 24QFN

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Thermal Resistance Junction to	$\theta_{\sf JA}$	Still air		29.1		°C/W
Ambient	$\theta_{\sf JA}$	1 m/s air flow		22.8		°C/W
	θ_{JA}	2.5 m/s air flow		21.0		°C/W
Thermal Resistance Junction to Case	$\theta_{\sf JC}$			41.8		°C/W

Package Outline and Package Dimensions (24-pin 4mm x 4mm QFN)

Package dimensions are kept current with JEDEC Publication No. 95



	Millimeters		
Symbol	Min	Max	
Α	0.80	1.00	
A1	0	0.05	
A3	0.25 Reference		
b	0.18	0.30	
е	0.50 BASIC		
N	24		
N _D	6		
N _E	6		
D x E BASIC	4.00 x 4.00		
D2	2.3	2.55	
E2	2.3	2.55	
L	0.30	0.50	

Ordering Information

Part / Order Number	Marking	Shipping Packaging	Package	Temperature
5P49EE602NLGI	See page 22	Tubes	24pin VFQFPN	-40 to +85° C
5P49EE602NLGI8	See page 22	Tape and Reel	24pin VFQFPN	-40 to +85° C

Parts that are ordered with a "G" after the two-letter package code are the Pb-Free configuration and are RoHS compliant.

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Revision History

Rev.	Originator	Date	Description of Change	
	R.Willner	10/16/09	Preliminary Datasheet release.	
Α	R.Willner	11/20/09	No_PD bit inclusion - 32kHz clock on/off in Config 00.	
В	R.Willner	3/26/10	Typographical changes. Correct spread spectrum calculations.	
С	R.Willner	6/11/10	Typographical changes. Default conditions.	

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